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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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## DATA SHEET



# MOS FIELD EFFECT TRANSISTOR

# NP90N055MUH, NP90N055NUH, NP90N055PUH

## SWITCHING **N-CHANNEL POWER MOS FET**

#### **DESCRIPTION**

The NP90N055MUH, NP90N055PUH are N-channel MOS Field Effect Transistors designed for high current switching applications.

#### ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE
NP90N055MUH-S18-AY Note		Tube	TO-220 (MP-25K) typ. 1.9 g
NP90N055NUH-S18-AY Note		50 p/tube	TO-262 (MP-25SK) typ. 1.8 g
NP90N055PUH-E1-AY Note	Pure Sn (Tin)	Tape	
NP90N055PUH-E2-AY Note		800 p/reel	TO-263 (MP-25ZP) typ. 1.5 g

Note Pb-free (This product does not contain Pb in the external electrode.)

#### **FEATURES**

- Enhancing Tch(MAX.) to 200°C (Operation time until 250 Hr)
- Super low on-state resistance
- NP90N055MUH, NP90N055NUH

 $R_{DS(on)} = 5.8 \text{ m}\Omega \text{ MAX}. \text{ (VGS = 10 V, ID = 45 A)}$ 

- NP90N055PUH

 $R_{DS(on)}$  = 5.4 m $\Omega$  MAX. (VGS = 10 V, ID = 45 A)

- · High avalanche energy, High avalanche current
- Low input capacitance

Ciss = 6200 pF TYP. (VDS = 25 V)

(TO-220)



(TO-262)





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## ABSOLUTE MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Drain to Source Voltage (Vss = 0 V)	VDSS	55	V
Gate to Source Voltage (V <sub>DS</sub> = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	I <sub>D(DC)</sub>	±90	Α
Drain Current (pulse) (Tc = 25°C) Note1	I <sub>D(pulse)</sub>	±360	Α
Total Power Dissipation (Tc = 25°C)	P <sub>T1</sub>	230	W
Total Power Dissipation (T <sub>A</sub> = 25°C)	P <sub>T2</sub>	1.8	W
Channel Temperature	T <sub>ch1</sub>	175	°C
Channel Temperature Note2	T <sub>ch2</sub>	200	°C
Storage Temperature	Tstg	-55 to +175	°C
Repetitive Avalanche Current Note3	lar1	65	Α
Repetitive Avalanche Current Note4	I <sub>AR2</sub>	70	Α
Repetitive Avalanche Energy Note5	Ear	1000	mJ

**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%

2. Reliability test condition

High temperature bias condition ( $V_{DS}$  =  $V_{DSS}$ ,  $V_{GS}$  = 0 V, 250 Hr) High temperature gate bias condition ( $V_{DS}$  = 0 V,  $V_{GS}$  = 20 V, 250 Hr)

- **3.** L = 100 μH, Tch ≤ 200°C
- **4.** L = 10  $\mu$ H, T<sub>ch</sub>  $\leq$  200°C
- **5.** Tch  $\leq$  200°C, Rg = 25  $\Omega$ , Vgs = 20  $\rightarrow$  0 V

#### THERMAL RESISTANCE

<R>

<R>

Channel to Case Thermal Resistance	Rth(ch-C)	0.65	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A)	83.3	°C/W



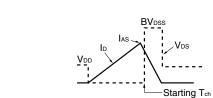
## **ELECTRICAL CHARACTERISTICS (TA = 25°C)**

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = 55 V, V <sub>GS</sub> = 0 V			1	μΑ
Gate Leakage Current	Igss	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V			±100	nA
Gate to Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.0	3.0	4.0	V
Forward Transfer Admittance Note	yfs	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 45 A	25	52		S
Drain to Source On-state Resistance Note	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 45 A NP90N055MUH, NP90N055NUH		4.6	5.8	mΩ
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 45 A NP90N055PUH		4.3	5.4	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = 25 V,		6200	9300	pF
Output Capacitance	Coss	V <sub>GS</sub> = 0 V,		820	1300	pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		250	450	pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 28 V, I <sub>D</sub> = 45 A,		27	60	ns
Rise Time	tr	V <sub>GS</sub> = 10 V,		14	35	ns
Turn-off Delay Time	td(off)	$R_G = 0 \Omega$		70	140	ns
Fall Time	tr			10	25	ns
Total Gate Charge	QG	V <sub>DD</sub> = 44 V,		100	150	nC
Gate to Source Charge	QGS	V <sub>GS</sub> = 10 V,		30		nC
Gate to Drain Charge	Q <sub>GD</sub>	I <sub>D</sub> = 90 A		30		nC
Body Diode Forward Voltage Note	V <sub>F(S-D)</sub>	I <sub>F</sub> = 90 A, V <sub>GS</sub> = 0 V		0.94	1.5	V
Reverse Recovery Time	trr	I <sub>F</sub> = 90 A, V <sub>GS</sub> = 0 V,		55		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		110		nC

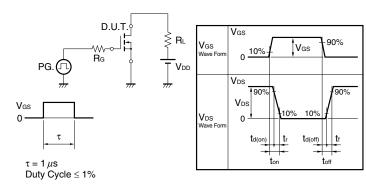
Note Pulsed

#### **TEST CIRCUIT 1 AVALANCHE CAPABILITY**

# $\begin{array}{c} \text{D.U.T.} \\ \text{RG} = 25 \ \Omega \\ \text{V} \\ \text{V} \\ \text{S} \\ \text{S} \\ \text{O} \\ \text{W} \\ \text{D} \\ \text{N} \\ \text$



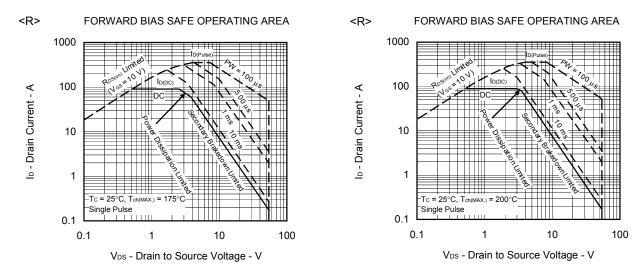
#### TEST CIRCUIT 2 SWITCHING TIME

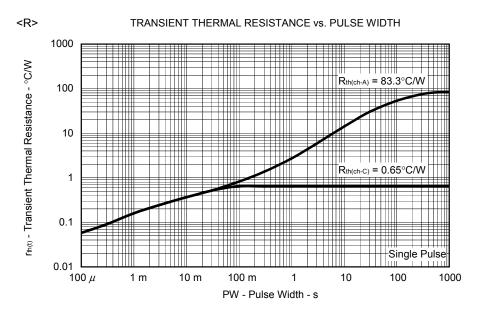


#### **TEST CIRCUIT 3 GATE CHARGE**

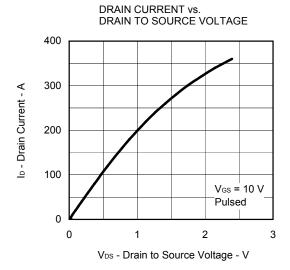
$$\begin{array}{c|c} D.U.T. \\ \hline I_G = 2 \text{ mA} \\ \hline \end{array} \begin{array}{c} PG. \\ \hline \end{array} \begin{array}{c} S \\ S \\ \end{array} \begin{array}{c} S \\ S \\ \end{array} \begin{array}{c} O.U.T. \\ \hline \end{array} \begin{array}{c} O.U.T. \\ \end{array} \begin{array}{c} O.U.T. \\$$

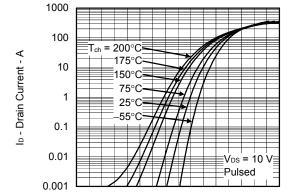
## TYPICAL CHARACTERISTICS (TA = 25°C) (NP90N055MUH)





**Note** Confirm the operation tracks are in Safe Operating Area.

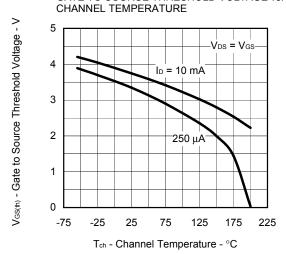




0 1 2 3

FORWARD TRANSFER CHARACTERISTICS

GATE TO SOURCE THRESHOLD VOLTAGE vs.

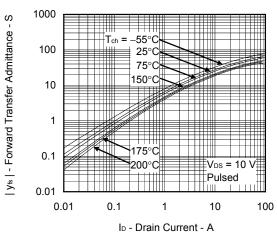


FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

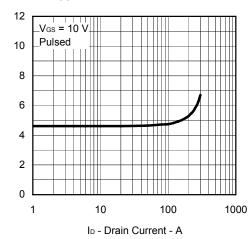
V<sub>GS</sub> - Gate to Source Voltage - V

5 6

8

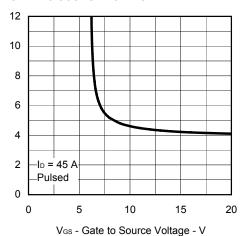


DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



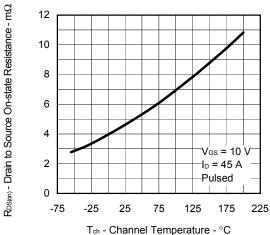
RDS(on) - Drain to Source On-state Resistance - m\Omega

DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

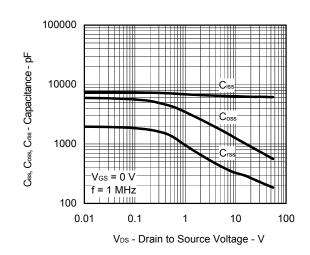


R<sub>DS(on)</sub> - Drain to Source On-state Resistance - mΩ

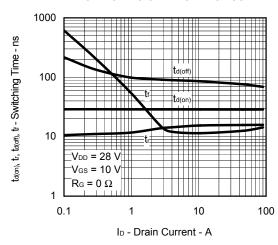




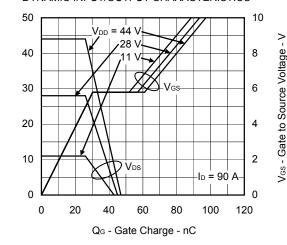
#### CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



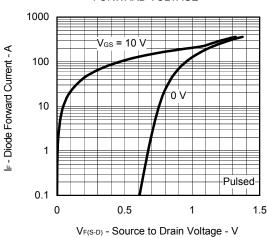
#### SWITCHING CHARACTERISTICS



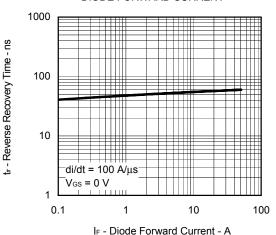
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



# SOURCE TO DRAIN DIODE FORWARD VOLTAGE

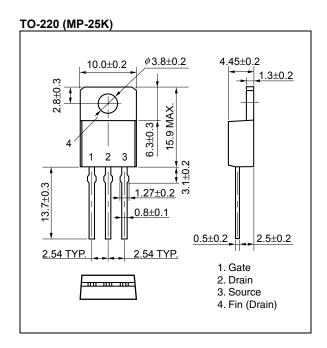


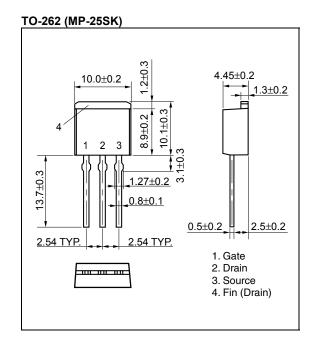
REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



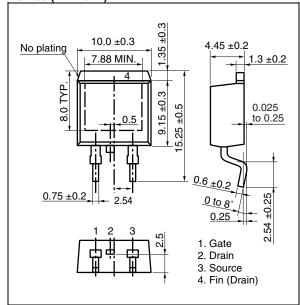
Vps - Drain to Source Voltage - V

#### PACKAGE DRAWINGS (Unit: mm)

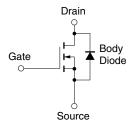




#### TO-263 (MP-25ZP)



## **EQUIVALENT CIRCUIT**

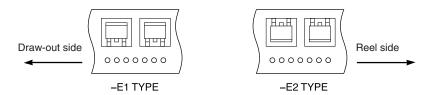


**Remark** Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

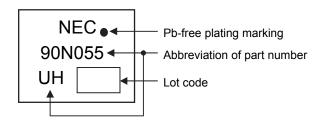


#### TAPE INFORMATION (NP90N055PUH)

There are two types (-E1, -E2) of taping depending on the direction of the device.



#### MARKING INFORMATION



#### RECOMMENDED SOLDERING CONDITIONS

These products should be soldered and mounted under the following recommended conditions.

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For technical information, see the following website.

Semiconductor Device Mount Manual (http://www.necel.com/pkg/en/mount/index.html)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow NP90N055PUH	Maximum temperature (Package's surface temperature): 260°C or below Time at maximum temperature: 10 seconds or less Time of temperature higher than 220°C: 60 seconds or less Preheating time at 160 to 180°C: 60 to 120 seconds Maximum number of reflow processes: 3 times Maximum chlorine content of rosin flux (percentage mass): 0.2% or less	IR60-00-3
Wave soldering NP90N055MUH, NP90N055NUH	Maximum temperature (Solder temperature): 260°C or below Time: 10 seconds or less Maximum chlorine content of rosin flux: 0.2% (wt.) or less	THDWS
Partial heating NP90N055MUH, NP90N055NUH, NP90N055PUH	Maximum temperature (Pin temperature): 350°C or below Time (per side of the device): 3 seconds or less Maximum chlorine content of rosin flux: 0.2% (wt.) or less	P350

Caution Do not use different soldering methods together (except for partial heating).

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